NSN 5961-01-645-6959

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-645-6959 **Inclosure Material:** Plastic **Overall Length:** Between 0.260 inches and 0.280 inches **Overall Height:** Between 0.075 inches and 0.095 inches **Overall Width:** Between 0.220 inches and 0.280 inches **End Application:** Landing gear system/components Voltage Rating In Volts Per Characteristic: 77.8 breakdown voltage, dc and 86.0 breakdown voltage, dc **Current Rating Per Characteristic:** 12.0 amperes forward current, dc **Product Name:** Diode transient abs **Terminal Type And Quantity:** 2 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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